# Low-Voltage CMOS Hex Inverter

# With 5 V-Tolerant Inputs

The MC74LCX04 is a high performance hex inverter operating from a 2.3 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A  $V_{\rm I}$  specification of 5.5 V allows MC74LCX04 inputs to be safely driven from 5 V devices.

Current drive capability is 24 mA at the outputs.

#### **Features**

- Designed for 2.3 V to 3.6 V V<sub>CC</sub> Operation
- 5 V Tolerant Inputs Interface Capability With 5 V TTL Logic
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current (10 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance: Human Body Model >2000 V;

Machine Model >200 V

• Pb-Free Packages are Available\*

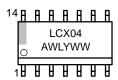


http://onsemi.com

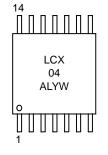
MARKING DIAGRAMS



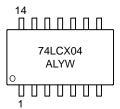
SOIC-14 D SUFFIX CASE 751A











A = Assembly Location

L, WL = Wafer Lot Y = Year W, WW = Work Week

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

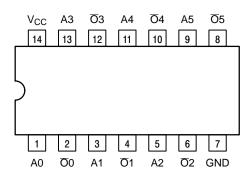


Figure 1. Pinout: 14-Lead (Top View)

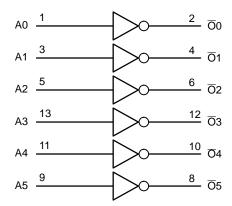


Figure 2. Logic Diagram

#### **PIN NAMES**

| Pins | Function    |
|------|-------------|
| An   | Data Inputs |
| Ōn   | Outputs     |

#### **TRUTH TABLE**

| An     | Ōn |
|--------|----|
| L<br>H | Н  |

#### **MAXIMUM RATINGS**

| Symbol           | Parameter                        | Value                             | Condition                            | Unit |
|------------------|----------------------------------|-----------------------------------|--------------------------------------|------|
| V <sub>CC</sub>  | DC Supply Voltage                | -0.5 to +7.0                      |                                      | V    |
| VI               | DC Input Voltage                 | $-0.5 \le V_1 \le +7.0$           |                                      | V    |
| Vo               | DC Output Voltage                | $-0.5 \le V_{O} \le V_{CC} + 0.5$ | Output in HIGH or LOW State (Note 1) | V    |
| I <sub>IK</sub>  | DC Input Diode Current           | -50                               | V <sub>I</sub> < GND                 | mA   |
| I <sub>OK</sub>  | DC Output Diode Current          | -50                               | V <sub>O</sub> < GND                 | mA   |
|                  |                                  | +50                               | V <sub>O</sub> > V <sub>CC</sub>     | mA   |
| Io               | DC Output Source/Sink Current    | ±50                               |                                      | mA   |
| I <sub>CC</sub>  | DC Supply Current Per Supply Pin | ±100                              |                                      | mA   |
| I <sub>GND</sub> | DC Ground Current Per Ground Pin | ±100                              |                                      | mA   |
| T <sub>STG</sub> | Storage Temperature Range        | -65 to +150                       |                                      | °C   |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

<sup>1.</sup> I<sub>O</sub> absolute maximum rating must be observed.

#### **RECOMMENDED OPERATING CONDITIONS**

| Symbol          | Pa                                 | rameter   | Min        | Туре                 | Max              | Unit |
|-----------------|------------------------------------|---|------------|----------------------|------------------|------|
| V <sub>CC</sub> | Supply Voltage                     | Operating Data Retention Only   | 2.0<br>1.5 | 2.5, 3.3<br>2.5, 3.3 | 3.6<br>3.6       | V    |
| VI              | Input Voltage                      |   | 0          |                      | 5.5              | V    |
| Vo              | Output Voltage                     | (HIGH or LOW State) (3–State)   | 0          |                      | V <sub>CC</sub>  | V    |
| I <sub>OH</sub> | HIGH Level Output Current          | V <sub>CC</sub> = 3.0 V - 3.6 V<br>V <sub>CC</sub> = 2.7 V - 3.0 V<br>V <sub>CC</sub> = 2.3 V - 2.7 V |            |                      | -24<br>-12<br>-8 | mA   |
| I <sub>OL</sub> | LOW Level Output Current           | V <sub>CC</sub> = 3.0 V - 3.6 V<br>V <sub>CC</sub> = 2.7 V - 3.0 V<br>V <sub>CC</sub> = 2.3 V - 2.7 V |            |                      | +24<br>+12<br>+8 | mA   |
| T <sub>A</sub>  | Operating Free-Air Temperature     |   | -40        |                      | +85              | °C   |
| Δt/ΔV           | Input Transition Rise or Fall Rate | , $V_{IN}$ from 0.8 V to 2.0 V, $V_{CC}$ = 3.0 V  | 0          |                      | 10               | ns/V |

# DC ELECTRICAL CHARACTERISTICS

|                 | Characteristic                        |   | T <sub>A</sub> = −40°C | to +85°C |      |
|-----------------|---------------------------------------|---|------------------------|----------|------|
| Symbol          |                                       | Condition   | Min                    | Max      | Unit |
| V <sub>IH</sub> | HIGH Level Input Voltage (Note 2)     | 2.3 V ≤ V <sub>CC</sub> ≤ 2.7 V   | 1.7                    |          | V    |
|                 |                                       | 2.7 V ≤ V <sub>CC</sub> ≤ 3.6 V   | 2.0                    |          |      |
| V <sub>IL</sub> | LOW Level Input Voltage (Note 2)      | 2.3 V ≤ V <sub>CC</sub> ≤ 2.7 V   |                        | 0.7      | V    |
|                 |                                       | 2.7 V ≤ V <sub>CC</sub> ≤ 3.6 V   |                        | 0.8      |      |
| V <sub>OH</sub> | HIGH Level Output Voltage             | $2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; \text{I}_{OH} = -100 \mu\text{A}$               | V <sub>CC</sub> – 0.2  |          | V    |
|                 |                                       | V <sub>CC</sub> = 2.3 V; I <sub>OH</sub> = -8 mA  | 1.8                    |          |      |
|                 |                                       | V <sub>CC</sub> = 2.7 V; I <sub>OH</sub> = -12 mA   | 2.2                    |          |      |
|                 |                                       | V <sub>CC</sub> = 3.0 V; I <sub>OH</sub> = -18 mA   | 2.4                    |          |      |
|                 |                                       | V <sub>CC</sub> = 3.0 V; I <sub>OH</sub> = -24 mA   | 2.2                    |          |      |
| V <sub>OL</sub> | LOW Level Output Voltage              | $2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; \text{I}_{OL} = 100 \mu\text{A}$                |                        | 0.2      | V    |
|                 |                                       | V <sub>CC</sub> = 2.3 V; I <sub>OL</sub> = 8 mA   |                        | 0.6      |      |
|                 |                                       | V <sub>CC</sub> = 2.7 V; I <sub>OL</sub> = 12 mA  |                        | 0.4      |      |
|                 |                                       | V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 16 mA  |                        | 0.4      |      |
|                 |                                       | V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 24 mA  |                        | 0.55     |      |
| I <sub>I</sub>  | Input Leakage Current                 | $2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; 0 \text{ V} \le \text{V}_{I} \le 5.5 \text{ V}$ |                        | ±5       | μΑ   |
| I <sub>CC</sub> | Quiescent Supply Current              | $2.3 \le V_{CC} \le 3.6 \text{ V}; V_I = \text{GND or } V_{CC}$                                     |                        | 10       | μΑ   |
|                 |                                       | $2.3 \le V_{CC} \le 3.6 \text{ V}; 3.6 \le V_{I} \text{ or } V_{O} \le 5.5 \text{ V}$               |                        | ±10      |      |
| $\Delta I_{CC}$ | Increase in I <sub>CC</sub> per Input | 2.3 ≤ V <sub>CC</sub> ≤ 3.6 V; V <sub>IH</sub> = V <sub>CC</sub> − 0.6 V                            |                        | 500      | μΑ   |

<sup>2.</sup> These values of  $\ensuremath{V_{I}}$  are used to test DC electrical characteristics only.

#### AC CHARACTERISTICS $t_R = t_F = 2.5 \text{ ns}; R_L = 500 \ \Omega$

|                  |                        |          |  |   | Lin              | nits  |                  |       |      |
|------------------|------------------------|----------|--|---|------------------|-------|------------------|-------|------|
|                  |                        |          |  | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ |                  |       |                  |       |      |
|                  |                        |          | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 2.7 \text{ V}$ $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ |   |                  |       |                  |       |      |
|                  |                        |          | C <sub>L</sub> =   | 50 pF   | C <sub>L</sub> = | 50 pF | C <sub>L</sub> = | 30 pF |      |
| Symbol           | Parameter              | Waveform | Min  | Max   | Min              | Max   | Min              | Max   | Unit |
| t <sub>PLH</sub> | Propagation Delay Time | 1        | 1.5  | 5.2   | 1.5              | 6.0   | 1.5              | 6.2   | ns   |
| t <sub>PHL</sub> | Input to Output        |          | 1.5  | 5.2   | 1.5              | 6.0   | 1.5              | 6.2   |      |
| toshl            | Output-to-Output Skew  |          |  | 1.0   |                  |       |                  |       | ns   |
| toslh            | (Note 3)               |          |  | 1.0   |                  |       |                  |       |      |

<sup>3.</sup> Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (toSHL) or LOW-to-HIGH (toSLH); parameter guaranteed by design.

#### **DYNAMIC SWITCHING CHARACTERISTICS**

|                  |                            |   | T <sub>A</sub> = +25°C |      |     |      |
|------------------|----------------------------|---|------------------------|------|-----|------|
| Symbol           | Characteristic             | Condition   | Min                    | Тур  | Max | Unit |
| V <sub>OLP</sub> | Dynamic LOW Peak Voltage   | $V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ |                        | 8.0  |     | V    |
|                  | (Note 4)                   | $V_{CC} = 2.5 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ |                        | 0.6  |     | V    |
| V <sub>OLV</sub> | Dynamic LOW Valley Voltage | $V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ |                        | -0.8 |     | V    |
|                  | (Note 4)                   | $V_{CC} = 2.5 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ |                        | -0.6 |     | V    |

<sup>4.</sup> Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

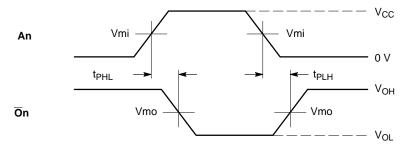
#### **CAPACITIVE CHARACTERISTICS**

| Symbol           | Parameter                     | Condition  | Typical | Unit |
|------------------|-------------------------------|--|---------|------|
| C <sub>IN</sub>  | Input Capacitance             | $V_{CC} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CC}$ | 7       | pF   |
| C <sub>OUT</sub> | Output Capacitance            | $V_{CC} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CC}$ | 8       | pF   |
| C <sub>PD</sub>  | Power Dissipation Capacitance | 10 MHz, $V_{CC}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CC}$    | 25      | pF   |

#### **ORDERING INFORMATION**

| Device        | Package              | Shipping <sup>†</sup> |
|---------------|----------------------|-----------------------|
| MC74LCX04D    | SOIC-14              | 55 Units / Rail       |
| MC74LCX04DR2  | SOIC-14              | 2500 Tape & Reel      |
| MC74LCX04DR2G | SOIC-14<br>(Pb-Free) | 2500 Tape & Reel      |
| MC74LCX04DT   | TSSOP-14*            | 96 Units / Rail       |
| MC74LCX04DTR2 | TSSOP-14*            | 2500 Tape & Reel      |
| MC74LCX04MEL  | SOEIAJ-14            | 2000 Tape & Reel      |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. \*This package is inherently Pb–Free.

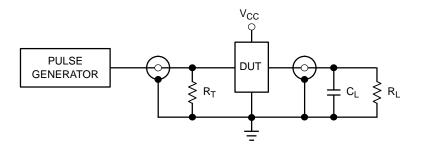


**WAVEFORM 1 - PROPAGATION DELAYS** 

 $t_R = t_F = 2.5 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$ 

|        | V <sub>CC</sub>   |       |                    |  |  |
|--------|-------------------|-------|--------------------|--|--|
| Symbol | 3.3 V $\pm$ 0.3 V | 2.7 V | 2.5 V $\pm$ 0.2 V  |  |  |
| Vmi    | 1.5 V             | 1.5 V | V <sub>CC</sub> /2 |  |  |
| Vmo    | 1.5 V             | 1.5 V | V <sub>CC</sub> /2 |  |  |

Figure 3. AC Waveforms



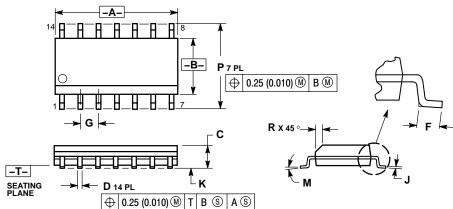
 $C_L$  = 50 pF at V<sub>CC</sub> = 3.3  $\pm 0.3$  V or equivalent (includes jig and probe capacitance)  $C_L$  = 30 pF at V<sub>CC</sub> = 2.5  $\pm 0.2$  V or equivalent (includes jig and probe capacitance)  $R_L$  =  $R_1$  = 500  $\Omega$  or equivalent

 $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

Figure 4. Test Circuit

#### PACKAGE DIMENSIONS

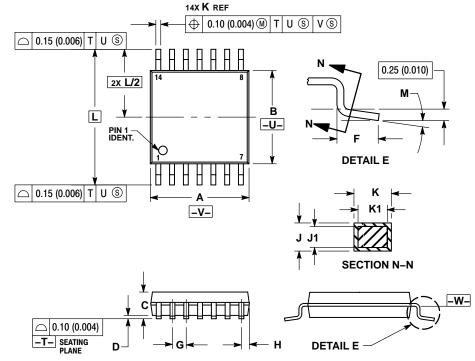
#### SOIC-14 **D SUFFIX** CASE 751A-03 ISSUE G



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
- 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE
  DAMBAR PROTRUSION. ALLOWABLE
  DAMBAR PROTRUSION SHALL BE 0.127
  (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

|     | MILLIN | IETERS | INC       | HES   |
|-----|--------|--------|-----------|-------|
| DIM | MIN    | MAX    | MIN       | MAX   |
| Α   | 8.55   | 8.75   | 0.337     | 0.344 |
| В   | 3.80   | 4.00   | 0.150     | 0.157 |
| С   | 1.35   | 1.75   | 0.054     | 0.068 |
| D   | 0.35   | 0.49   | 0.014     | 0.019 |
| F   | 0.40   | 1.25   | 0.016     | 0.049 |
| G   | 1.27   | BSC    | 0.050 BSC |       |
| J   | 0.19   | 0.25   | 0.008     | 0.009 |
| K   | 0.10   | 0.25   | 0.004     | 0.009 |
| M   | 0 °    | 7°     | 0 °       | 7°    |
| Р   | 5.80   | 6.20   | 0.228     | 0.244 |
| R   | 0.25   | 0.50   | 0.010     | 0.019 |

#### TSSOP-14 **DT SUFFIX** CASE 948G-01 **ISSUE O**



- OTES.

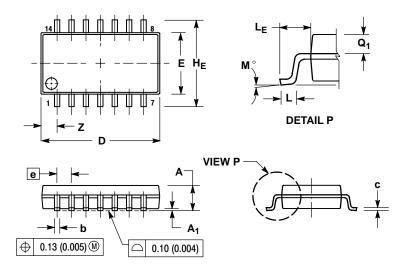
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.
- 2. OMTHOLIUM DIMELTION, MILEUITETT.
  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH,
  PROTRUSIONS OR GATE BURRS. MOLD FLASH
  OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED
- 0.25 (0.010) PER SIDE.
  5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
  DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

|     | MILLIMETERS |      | INC       | HES   |
|-----|-------------|------|-----------|-------|
| DIM | MIN         | MAX  | MIN       | MAX   |
| Α   | 4.90        | 5.10 | 0.193     | 0.200 |
| В   | 4.30        | 4.50 | 0.169     | 0.177 |
| С   |             | 1.20 |           | 0.047 |
| D   | 0.05        | 0.15 | 0.002     | 0.006 |
| F   | 0.50        | 0.75 | 0.020     | 0.030 |
| G   | 0.65        | BSC  | 0.026 BSC |       |
| Н   | 0.50        | 0.60 | 0.020     | 0.024 |
| J   | 0.09        | 0.20 | 0.004     | 0.008 |
| J1  | 0.09        | 0.16 | 0.004     | 0.006 |
| K   | 0.19        | 0.30 | 0.007     | 0.012 |
| K1  | 0.19        | 0.25 | 0.007     | 0.010 |
| L   | 6.40        |      | 0.252     | BSC   |
| M   | 0°          | 8°   | 0°        | 8°    |

#### **PACKAGE DIMENSIONS**

SOEIAJ-14 **M SUFFIX** CASE 965-01 **ISSUE O** 



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
  5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER DIMENSION AT MAXIMUM MATEHIAL CONDITION.

  DAMBAR CANNOT BE LOCATED ON THE LOWER
  RADIUS OR THE FOOT. MINIMUM SPACE
  BETWEEN PROTRUSIONS AND ADJACENT LEAD
  TO BE 0.46 (0.018).

|                | MILLIMETERS |       | INCHES    |       |
|----------------|-------------|-------|-----------|-------|
| DIM            | MIN         | MAX   | MIN       | MAX   |
| Α              |             | 2.05  |           | 0.081 |
| A <sub>1</sub> | 0.05        | 0.20  | 0.002     | 0.008 |
| b              | 0.35        | 0.50  | 0.014     | 0.020 |
| C              | 0.18        | 0.27  | 0.007     | 0.011 |
| D              | 9.90        | 10.50 | 0.390     | 0.413 |
| E              | 5.10        | 5.45  | 0.201     | 0.215 |
| е              | 1.27 BSC    |       | 0.050 BSC |       |
| HE             | 7.40        | 8.20  | 0.291     | 0.323 |
| L              | 0.50        | 0.85  | 0.020     | 0.033 |
| LE             | 1.10        | 1.50  | 0.043     | 0.059 |
| M              | 0 °         | 10°   | 0 °       | 10°   |
| Q <sub>1</sub> | 0.70        | 0.90  | 0.028     | 0.035 |
| Z              |             | 1.42  |           | 0.056 |

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